

FTO-1221U

SINGLE CHANNEL-SURFACE MOUNT OPTOCOUPLER

FORCE
TECHNOLOGIES LTD
www.forcetechnologies.co.uk

Features:

- High Reliability
- No base lead for improved noise immunity
- Rugged surface mount package
- Stability over wide temperature
- +1kV ELECTRICAL isolation

Applications:

- Eliminate ground loops
- Level shifting
- Line receiver
- Switching power supplies
- Motor control

DESCRIPTION

The **FTO-1221U** contains a gallium aluminum arsenide LED optically coupled to a silicon planar phototransistor. The optocoupler is built in a 4 pin leadless chip carrier. This optocoupler is capable of transmitting signals between two galvanic sources. The potential difference between transmitter and receiver should not go over the maximum isolation voltage. The internal base connection has been eliminated for improved noise immunity.

ABSOLUTE MAXIMUM RATINGS

Input to Output Voltage.....	1000V
Emitter-Collector Voltage.....	5V
Collector-Emitter Voltage (Value applies to emitter-base open-circuited & the input-diode equal to zero).....	35V
Reverse Input Voltage	2V
Input Diode Continuous Forward Current at (or below) 65°C Free-Air Temperature (see note 1)	40mA
Continuous Collector Current.....	50mA
Continuous Transistor Power Dissipation at (or below) 25°C Free-Air Temperature (see Note 2)	300mW
Storage Temperature.....	-65°C to +150°C
Operating Free-Air Temperature Range.....	-55°C to +125°C
Lead Solder Temperature (10 seconds max.)	240°C

Notes:

1. Derate linearly to 125°C free-air temperature at the rate of 0.67 mA/°C above 65°C.
2. Derate linearly to 125°C free-air temperature at the rate of 3 mW/°C.

RECOMMENDED OPERATING CONDITIONS:

PARAMETER	SYMBOL	MIN	MAX	UNIT
Input Current, Low Level	I _{FL}	0	1	µA
Input Current, High Level	I _{FH}	1.5	10	mA
Supply Voltage	V _{CE}	5	50	V
Operating Temperature	T _A	-55	125	°C

SELECTION GUIDE

PART NUMBER	PART DESCRIPTION
FTO-1221U-001	Single Channel optocoupler, commercial (-55° to +125°C operating temperature range)
FTO-1221U-101	Single Channel optocoupler, TX Processed (-55° to +125°C operating temperature range)



SINGLE CHANNEL OPTOCOUPLED

ELECTRICAL CHARACTERISTICS

INPUT DIODE

$T_A = 25^\circ\text{C}$ unless otherwise specified.

PARAMETER	SYMBOL	MIN	MAX	UNIT	TEST CONDITIONS
Input Diode Static Reverse Current	I_R		100	μA	$V_R = 2.0\text{V}$
Input Diode Static Forward Voltage	V_F		1.5	V	$I_F = 10\text{mA}$
Input Diode Static Forward Voltage 55°C	V_F		1.7	V	$I_F = 10\text{mA}$
Input Diode Static Forward Voltage $+125^\circ\text{C}$	V_F		1.3	V	$I_F = 10\text{mA}$

OUTPUT TRANSISTOR

$T_A = 25^\circ\text{C}$ unless otherwise specified.

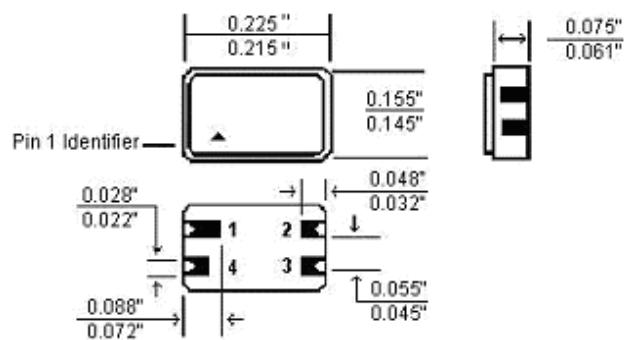
PARAMETER	SYMBOL	MIN	MAX	UNIT	TEST CONDITIONS
Collector-Emitter Breakdown Voltage	$V_{(\text{BR})\text{CEO}}$	30		V	$I_C = 1\text{mA}, I_B = 0, I_F = 0$
Emitter-Collector Breakdown Voltage	$V_{(\text{BR})\text{ECO}}$	5		V	$I_C = 0\text{mA}, I_E = 100\mu\text{A}, I_F = 0$
Collector-Emitter Dark Current 55°C	$I_{\text{CEO}1}$		100	nA	
	$I_{\text{CEO}2}$		100	nA	
	$I_{\text{CEO}3}$		100	μA	$V_{\text{CE}} = 20\text{V}, I_F = 0\text{mA}$
$+125^\circ\text{C}$					

COUPLED CHARACTERISTICS

$T_A = 25^\circ\text{C}$ unless otherwise specified.

PARAMETER	SYMBOL	MIN	MAX	UNIT	TEST CONDITIONS
On State Collector Current	$I_{C(\text{ON})1}$	2.0		mA	$V_{\text{CE}} = 1\text{V}, I_F = 1.0\text{mA}$
On State Collector Current	$I_{C(\text{ON})2}$	15.0		mA	$V_{\text{CE}} = 1\text{V}, I_F = 15\text{mA}$
On State Collector Current	$I_{C(\text{ON})3}$	40.0		mA	$V_{\text{CE}} = 5\text{V}, I_F = 10.0\text{mA}$
On State Collector Current	$I_{C(\text{ON})4}$	15.0		mA	$V_{\text{CE}} = 5\text{V}, I_F = 15\text{mA}$
On State Collector Current	$I_{C(\text{ON})5}$	1.0		mA	$V_{\text{CE}} = 15\text{V}, I_F = 1.0\text{mA}$
On State Collector Current	$I_{C(\text{ON})}$	2.5		mA	$V_{\text{CE}} = 5\text{V}, I_F = 1.5\text{mA}, T_A = -55^\circ\text{C}$
On State Collector Current	$I_{C(\text{ON})}$	2.5		mA	$V_{\text{CE}} = 5\text{V}, I_F = 1.5\text{mA}, T_A = +125^\circ\text{C}$
Collector-Emitter Saturation Voltage	$V_{\text{CE}(\text{SAT})}$		0.22	V	$I_F = 20\text{mA}, I_C = 10\text{mA}$
Isolation Resistance	R_{ISO}	10^5		Ω	$V_{\text{IN-OUT}} = 500\text{V}$
Isolation Voltage	V_{ISO}	1050			$t = 5\text{s}$
Propagation Delay H-L	t_{PHL}		4.0		$V_{\text{CC}} = 10\text{V}, I_F = 10.0\text{mA}, R_L = 100\Omega$
Propagation Delay L-H	t_{PLH}		4.0		$V_{\text{CC}} = 10\text{V}, I_F = 10.0\text{mA}, R_L = 100\Omega$
Rise Time	t_r		20	μs	$V_{\text{CC}} = 10\text{V}, I_F = 10.0\text{mA}, R_L = 100\Omega$
Fall Time	t_f		20	μs	$V_{\text{CC}} = 10\text{V}, I_F = 10.0\text{mA}, R_L = 100\Omega$

Package Dimensions



Schematic Diagram

